IN THE SPECIFICATION:

Page 12, lines 17-20:

If the intensity of an individual active zone $\frac{AZn_{\ell}}{2}$ such as AZ3 (light-emitting diode) - as shown in Fig. 4a, b - exhibits a brighter or more intense peak 20, it is possible to place an absorption layer $\frac{ABS}{2}$ $\frac{Abs}{2}$ of suitable thickness, and made of the same material from which the pn layer $\frac{AZ3}{2}$ is made, directly on top of the active zone $\frac{AZ3}{2}$.